



PRODUCT NAME : PN3638 PNP General Purpose Transistor (Pack of 5)

PRICE : Rs 20.00

SKU : RM2041



NOTE: THE PRODUCT MAY BE DIFFERENT FROM IMAGE SHOWN. Copyrights by Robomart.com

DESCRIPTION

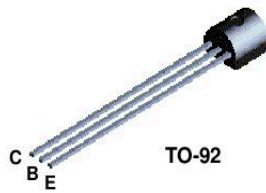
Features

- Collector-Emitter Volt (V_{ce0}): 25V
- Collector-Base Volt (V_{cb0}): 25V
- Collector Current (I_c): 0.8A
- h_{fe} : 30 @ 50mA
- Power Dissipation (P_{tot}): 625mW
- Current-Gain-Bandwidth (f_{total}): -
- Type: PNP



*Discrete POWER & Signal
Technologies*

**PN3638
PN3638A**



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 63. See PN2907A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	25	V
V _{EBO}	Emitter-Base Voltage	4.9	V
I _C	Collector Current - Continuous	800	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		PN3638/A	
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	83.3	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	200	°C/W

PNP General Purpose Amplifier
(continued)

Electrical Characteristics TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 10\text{ mA}, I_B = 0$	25		V
$V_{(BR)CES}$	Collector-Emitter Breakdown Voltage*	$I_C = 100\text{ }\mu\text{A}, I_B = 0$	25		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 10\text{ }\mu\text{A}, I_E = 0$	25		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10\text{ }\mu\text{A}, I_C = 0$	4.0		V
I_{CES}	Collector-Cutoff Current	$V_{CE} = 15\text{ V}, I_E = 0$ $V_{CE} = 15\text{ V}, I_E = 0, T_A = 65^\circ\text{C}$		35 2.0	nA μA

ON CHARACTERISTICS*

h_{FE}	DC Current Gain	$V_{CE} = 1.0\text{ V}, I_C = 50\text{ mA}$ PN3638 PN3638A $V_{CE} = 2.0\text{ V}, I_C = 300\text{ mA}$ PN3638 PN3638A $V_{CE} = 10\text{ V}, I_C = 100\text{ mA}$ PN3638 PN3638A $V_{CE} = 10\text{ V}, I_C = 1.0\text{ mA}$ PN3638A	30 100 30 20 20 80 100		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 50\text{ mA}, I_B = 2.5\text{ mA}$ $I_C = 300\text{ mA}, I_B = 30\text{ mA}$		0.25 1.0	V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 50\text{ mA}, I_B = 2.5\text{ mA}$ $I_C = 300\text{ mA}, I_B = 30\text{ mA}$	0.8	1.1 2.0	V V

SMALL SIGNAL CHARACTERISTICS

C_{ob}	Output Capacitance	$V_{CB} = 10\text{ V}, f = 1.0\text{ MHz}$ PN3638 PN3638A		20 10	pF pF
C_{ib}	Input Capacitance	$V_{BE} = 0.5\text{ V}, f = 1.0\text{ MHz}$ PN3638 PN3638A		65 25	pF pF
h_{ie}	Small-Signal Current Gain	$I_C = 50\text{ mA}, V_{CE} = 3.0\text{ V}, f = 100\text{ MHz}$ PN3638 PN3638A $I_C = 10\text{ mA}, V_{CE} = 10\text{ V}, f = 1.0\text{ kHz}$ PN3638 PN3638A	1.0 1.5 25 100		
h_{ie}	Input Impedance	$I_C = 10\text{ mA}, V_{CE} = 10\text{ V}, f = 1.0\text{ kHz}$		2.0	$k\Omega$
h_{oe}	Output Admittance			1.2	μmhos
h_{re}	Voltage Feedback Ratio	PN3638 PN3638A		26 15	$\times 10^{-4}$ $\times 10^{-4}$

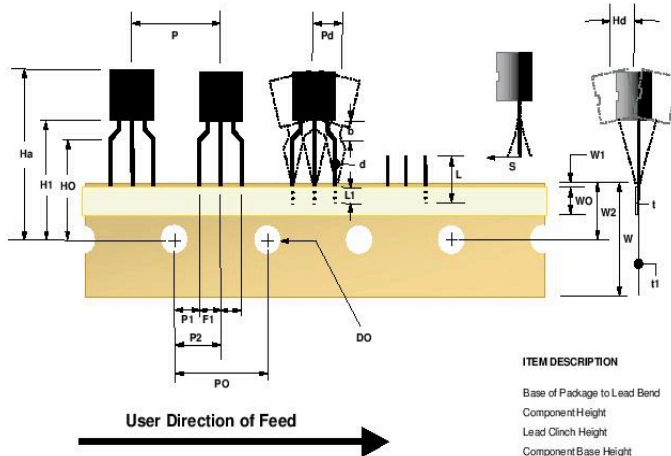
SWITCHING CHARACTERISTICS

t_{on}	Turn-on Time	$V_{CC} = 10\text{ V}, I_C = 300\text{ mA}, I_{B1} = 30\text{ mA}$	75		ns
t_d	Delay Time		20		ns
t_r	Rise Time		70		ns
t_{off}	Turn-off Time	$V_{CC} = 10\text{ V}, I_C = 300\text{ mA}, I_{B1} = I_{B2} = 30\text{ mA}$	170		ns
t_s	Storage Time		140		ns
t_f	Fall Time		70		ns

* Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$

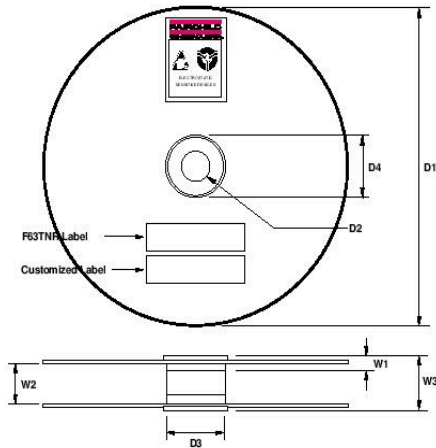
TO-92 Tape and Reel Data, continued

TO-92 Tape and Reel Taping
 Dimension Configuration: Figure 4.0



ITEM DESCRIPTION	SYMBOL	DIMENSION
Base of Package to Lead Bend	b	0.08 (max)
Component Height	Ha	0.928 (+/- 0.025)
Lead Clinch Height	HO	0.630 (+/- 0.020)
Component Base Height	H1	0.748 (+/- 0.020)
Component Alignment (side/side)	Pd	0.040 (max)
Component Alignment (front/back)	Hd	0.031 (max)
Component Pitch	P	0.500 (+/- 0.020)
Feed Hole Pitch	PO	0.500 (+/- 0.008)
Hole Center to First Lead	P1	0.150 (+0.009, -0.010)
Hole Center to Component Center	P2	0.247 (+/- 0.007)
Lead Spread	F1/F2	0.104 (+/- 0.010)
Lead Thickness	d	0.018 (+0.002, -0.003)
Cut Lead Length	L	0.429 (max)
Taped Lead Length	L1	0.209 (+0.051, -0.052)
Taped Lead Thickness	t	0.032 (+/- 0.006)
Carrier Tape Thickness	tt	0.021 (+/- 0.006)
Carrier Tape Width	W	0.708 (+0.020, -0.019)
Hold - down Tape Width	W0	0.235 (+/- 0.012)
Hold - down Tape position	W1	0.035 (max)
Feed Hole Position	W2	0.360 (+/- 0.025)
Sprocket Hole Diameter	DO	0.157 (+0.008, -0.007)
Lead Spring Out	S	0.004 (max)

TO-92 Reel
 Configuration: Figure 5.0



Note : All dimensions are in inches.

ITEM DESCRIPTION	SYMBOL	MINIMUM	MAXIMUM
Reel Diameter	D1	13.975	14.025
Arbor Hole Diameter (Standard)	D2	1.160	1.200
(Small Hole)	D2	0.650	0.700
Core Diameter	D3	3.100	3.300
Hub Recess Inner Diameter	D4	2.700	3.100
Hub Recess Depth	W1	0.370	0.570
Flange to Flange Inner Width	W2	1.630	1.690
Hub to Hub Center Width	W3		2.090

Note: All dimensions are inches

July 1999, Rev. A

